

SUPPORTING INFORMATION

Impact of Doping on GO: Fast Response–Recovery Humidity Sensor

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Figure S1. Schematic synthesis process of undoped GO, Li-doped GO and B-doped GO

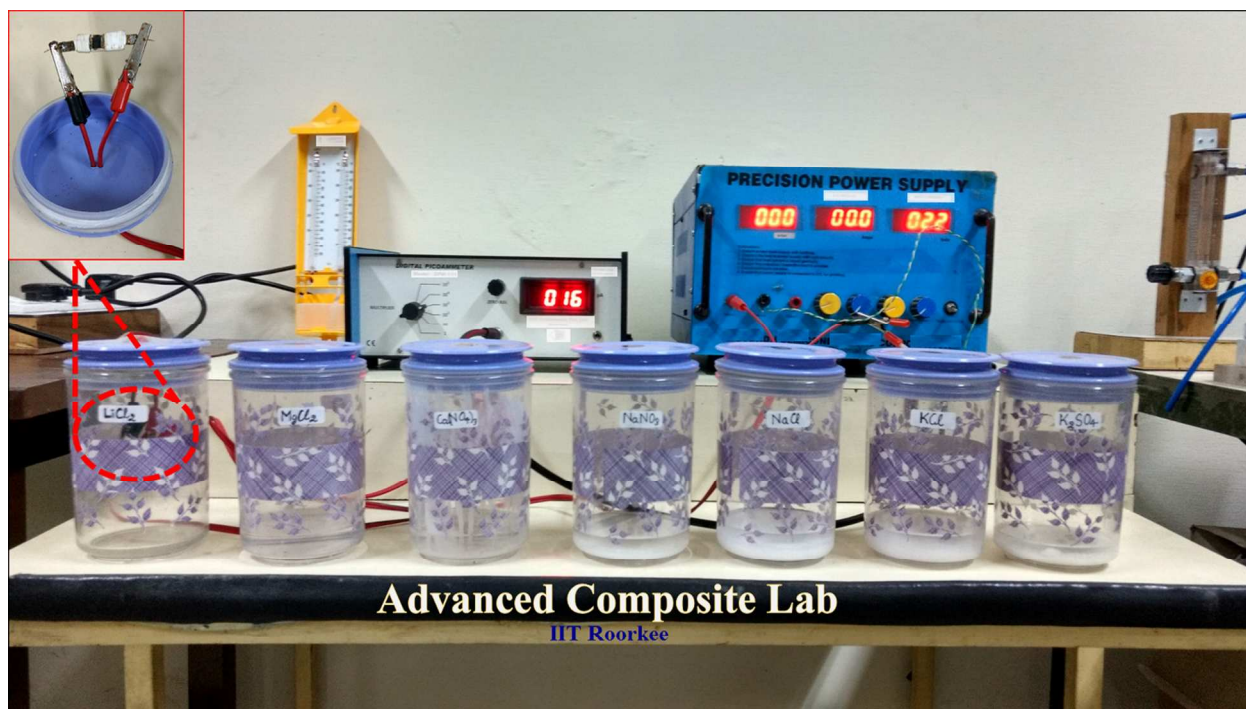


Figure S2. Experimental setup for humidity sensing test facility with necessary accessories (inset the fabrication of the sensor)